

HEF4094B

8-stage shift-and-store bus register

Rev. 07 — 16 December 2009

Product data sheet

1. General description

The HEF4094B is an 8-stage serial shift register. It has a storage latch associated with each stage for strobing data from the serial input to parallel buffered 3-state outputs QP0 to QP7. The parallel outputs may be connected directly to common bus lines. Data is shifted on positive-going clock transitions. The data in each shift register stage is transferred to the storage register when the strobe (STR) input is HIGH. Data in the storage register appears at the outputs whenever the output enable (OE) signal is HIGH.

Two serial outputs (QS1 and QS2) are available for cascading a number of HEF4094B devices. Serial data is available at QS1 on positive-going clock edges to allow high-speed operation in cascaded systems with a fast clock rise time. The same serial data is available at QS2 on the next negative going clock edge. This is used for cascading HEF4094B devices when the clock has a slow rise time.

It operates over a recommended V_{DD} power supply range of 3 V to 15 V referenced to V_{SS} (usually ground). Unused inputs must be connected to V_{DD} , V_{SS} , or another input. It is also suitable for use over the industrial ($-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$) and automotive ($-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$) temperature ranges.

2. Features

- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Operates across the automotive temperature range $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$
- Complies with JEDEC standard JESD 13-B

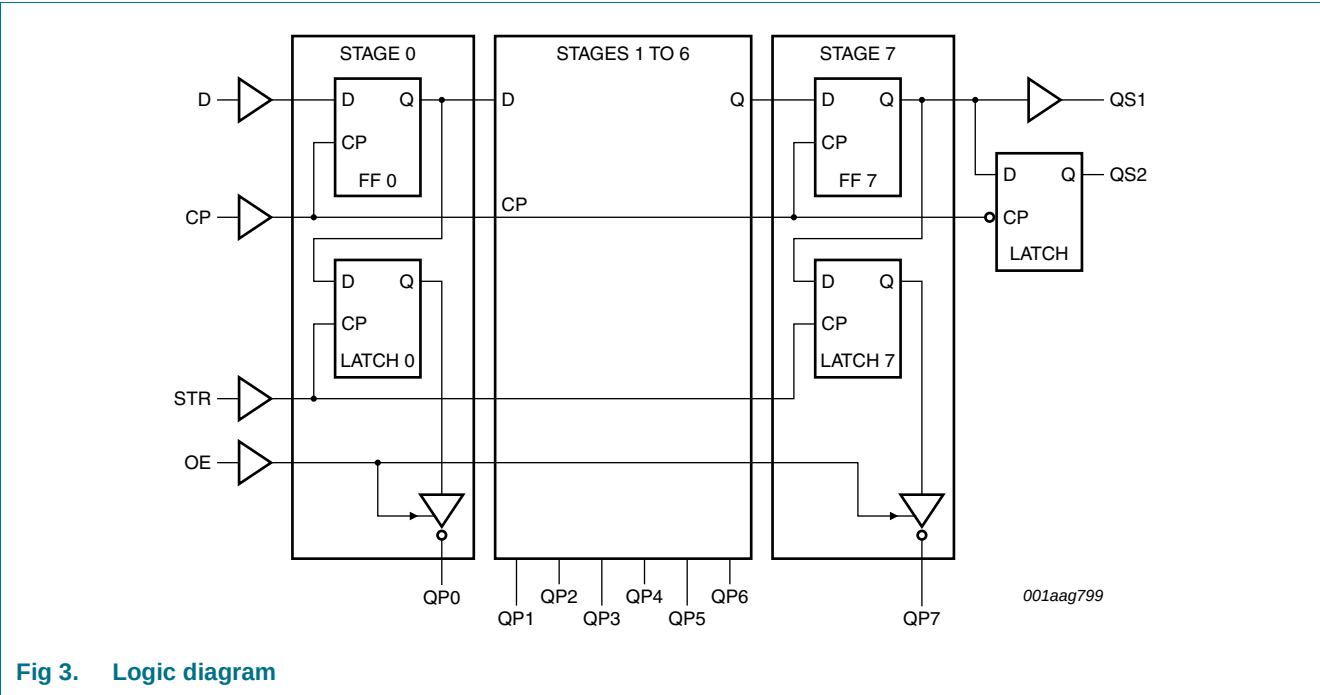
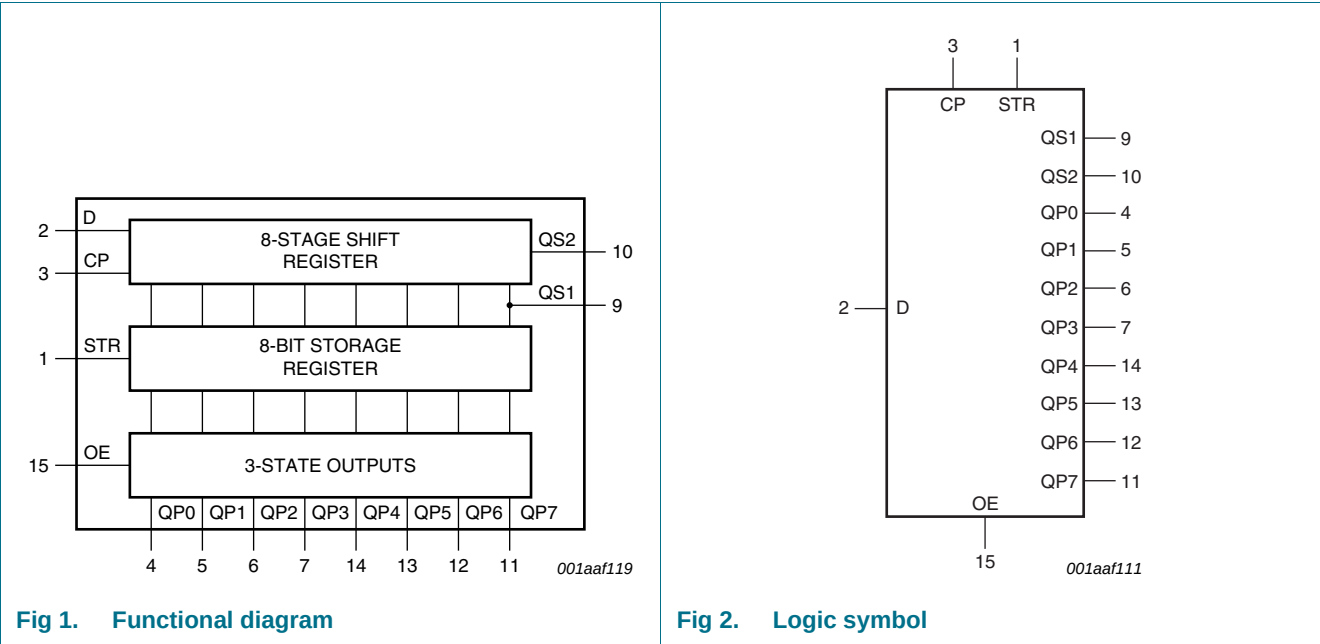
3. Ordering information

Table 1. Ordering information

All types operate from $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$.

Type number	Package		
	Name	Description	Version
HEF4094BP	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4
HEF4094BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
HEF4094BTS	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1

4. Functional diagram



5. Pinning information

5.1 Pinning

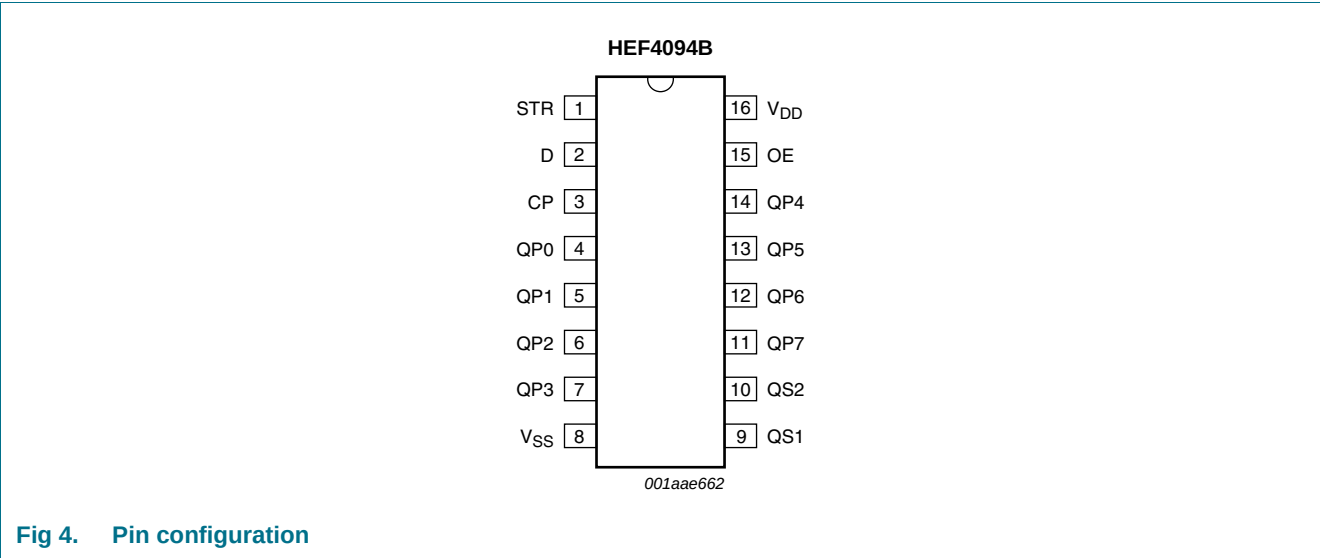


Fig 4. Pin configuration

5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
STR	1	strobe input
D	2	data input
CP	3	clock input
QP0 to QP7	4, 5, 6, 7, 14, 13, 12, 11	parallel output
V _{SS}	8	ground supply voltage
QS1	9	serial output
QS2	10	serial output
OE	15	output enable input
V _{DD}	16	supply voltage

6. Functional description

Table 3. Function table^[1]

Inputs				Parallel outputs		Serial outputs	
CP	OE	STR	D	QP0	QPn	QS1	QS2
↑	L	X	X	Z	Z	Q6S	NC
↓	L	X	X	Z	Z	NC	Q7S
↑	H	L	X	NC	NC	Q6S	NC
↑	H	H	L	L	QPn –1	Q6S	NC
↑	H	H	H	H	QPn –1	Q6S	NC
↓	H	H	H	NC	NC	NC	Q7S

[1] At the positive clock edge, the information in the 7th register stage is transferred to the 8th register stage and the QSn outputs.

H = HIGH voltage level; L = LOW voltage level; X = don't care;

↑ = positive-going transition; ↓ = negative-going transition;

Z = HIGH-impedance OFF-state; NC = no change;

Q6S = the data in register stage 6 before the LOW to HIGH clock transition;

Q7S = the data in register stage 7 before the HIGH to LOW clock transition.

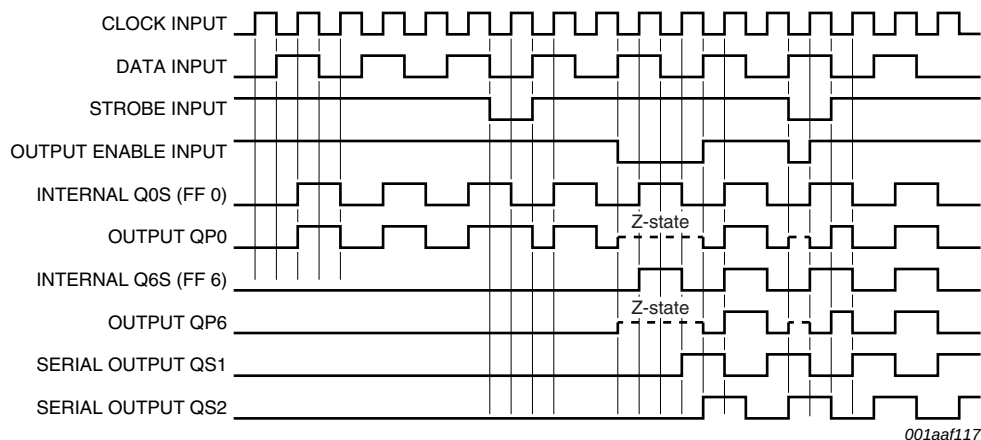


Fig 5. Timing diagram

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to $V_{SS} = 0$ V (ground).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DD}	supply voltage		-0.5	+18	V
I_{IK}	input clamping current	$V_I < -0.5$ V or $V_I > V_{DD} + 0.5$ V	-	± 10	mA
V_I	input voltage		-0.5	$V_{DD} + 0.5$	V
I_{OK}	output clamping current	$V_O < -0.5$ V or $V_O > V_{DD} + 0.5$ V	-	± 10	mA
$I_{I/O}$	input/output current		-	± 10	mA
I_{DD}	supply current		-	50	mA
T_{stg}	storage temperature		-65	+150	°C
T_{amb}	ambient temperature		-40	+125	°C
P_{tot}	total power dissipation	DIP16	[1] -	750	mW
		SO16	[2] -	500	mW
P	power dissipation	per output	-	100	mW

[1] For DIP16 packages: above $T_{amb} = 70$ °C, P_{tot} derates linearly with 12 mW/K.

[2] For SO16 packages: above $T_{amb} = 70$ °C, P_{tot} derates linearly with 8 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DD}	supply voltage		3	-	15	V
V_I	input voltage		0	-	V_{DD}	V
T_{amb}	ambient temperature	in free air	-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{DD} = 5$ V	-	-	3.75	$\mu\text{s/V}$
		$V_{DD} = 10$ V	-	-	0.5	$\mu\text{s/V}$
		$V_{DD} = 15$ V	-	-	0.08	$\mu\text{s/V}$

9. Static characteristics

Table 6. Static characteristics

$V_{SS} = 0\text{ V}$; $V_I = V_{SS}$ or V_{DD} ; unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	$T_{amb} = -40\text{ °C}$		$T_{amb} = +25\text{ °C}$		$T_{amb} = +85\text{ °C}$		$T_{amb} = +125\text{ °C}$		Unit
				Min	Max	Min	Max	Min	Max	Min	Max	
V_{IH}	HIGH-level input voltage	$ I_O < 1\text{ }\mu\text{A}$	5 V	3.5	-	3.5	-	3.5	-	3.5	-	V
			10 V	7.0	-	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	11.0	-	V
V_{IL}	LOW-level input voltage	$ I_O < 1\text{ }\mu\text{A}$	5 V	-	1.5	-	1.5	-	1.5	-	1.5	V
			10 V	-	3.0	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	-	4.0	V
V_{OH}	HIGH-level output voltage	$ I_O < 1\text{ }\mu\text{A}$	5 V	4.95	-	4.95	-	4.95	-	4.95	-	V
			10 V	9.95	-	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	14.95	-	V
V_{OL}	LOW-level output voltage	$ I_O < 1\text{ }\mu\text{A}$	5 V	-	0.05	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	-	0.05	V
I_{OH}	HIGH-level output current	$V_O = 2.5\text{ V}$	5 V	-1.7	-	-1.4	-	-1.1	-	-1.1	-	mA
		$V_O = 4.6\text{ V}$	5 V	-0.64	-	-0.5	-	-0.36	-	-0.36	-	mA
		$V_O = 9.5\text{ V}$	10 V	-1.6	-	-1.3	-	-0.9	-	-0.9	-	mA
		$V_O = 13.5\text{ V}$	15 V	-4.2	-	-3.4	-	-2.4	-	-2.4	-	mA
I_{OL}	LOW-level output current	$V_O = 0.4\text{ V}$	5 V	0.64	-	0.5	-	0.36	-	0.36	-	mA
		$V_O = 0.5\text{ V}$	10 V	1.6	-	1.3	-	0.9	-	0.9	-	mA
		$V_O = 1.5\text{ V}$	15 V	4.2	-	3.4	-	2.4	-	2.4	-	mA
I_{OZ}	OFF-state output current	QPn output is HIGH; $V_O = 15\text{ V}$	15 V	-	0.4	-	0.4	-	12	-	12	μA
I_I	input leakage current		15 V	-	± 0.1	-	± 0.1	-	± 1.0	-	± 1.0	μA
I_{DD}	supply current	all valid input combinations; $I_O = 0\text{ A}$	5 V	-	5	-	5	-	150	-	150	μA
			10 V	-	10	-	10	-	300	-	300	μA
			15 V	-	20	-	20	-	600	-	600	μA
C_I	input capacitance			-	-	-	7.5	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

$V_{SS} = 0\text{ V}$; $T_{amb} = 25\text{ °C}$; for test circuit see [Figure 10](#); unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	Extrapolation formula	Min	Typ	Max	Unit
t_{PHL}	HIGH to LOW propagation delay	CP to QS1; see Figure 6	5 V	[1] $108\text{ ns} + (0.55\text{ ns/pF}) C_L$	-	135	270	ns
			10 V	$54\text{ ns} + (0.23\text{ ns/pF}) C_L$	-	65	130	ns
			15 V	$42\text{ ns} + (0.16\text{ ns/pF}) C_L$	-	50	100	ns
		CP to QS2; see Figure 6	5 V	$78\text{ ns} + (0.55\text{ ns/pF}) C_L$	-	105	210	ns
			10 V	$39\text{ ns} + (0.23\text{ ns/pF}) C_L$	-	50	100	ns
			15 V	$32\text{ ns} + (0.16\text{ ns/pF}) C_L$	-	40	80	ns
		CP to QPn; see Figure 6	5 V	$138\text{ ns} + (0.55\text{ ns/pF}) C_L$	-	165	330	ns
			10 V	$64\text{ ns} + (0.23\text{ ns/pF}) C_L$	-	75	150	ns
			15 V	$47\text{ ns} + (0.16\text{ ns/pF}) C_L$	-	55	110	ns
		STR to QPn; see Figure 7	5 V	$83\text{ ns} + (0.55\text{ ns/pF}) C_L$	-	110	220	ns
			10 V	$39\text{ ns} + (0.23\text{ ns/pF}) C_L$	-	50	100	ns
			15 V	$27\text{ ns} + (0.16\text{ ns/pF}) C_L$	-	35	70	ns
t_{PLH}	LOW to HIGH propagation delay,	CP to QS1; see Figure 6	5 V	[1] $78\text{ ns} + (0.55\text{ ns/pF}) C_L$	-	105	210	ns
			10 V	$39\text{ ns} + (0.23\text{ ns/pF}) C_L$	-	50	100	ns
			15 V	$32\text{ ns} + (0.16\text{ ns/pF}) C_L$	-	40	80	ns
		CP to QS2; see Figure 6	5 V	$78\text{ ns} + (0.55\text{ ns/pF}) C_L$	-	105	210	ns
			10 V	$39\text{ ns} + (0.23\text{ ns/pF}) C_L$	-	50	100	ns
			15 V	$32\text{ ns} + (0.16\text{ ns/pF}) C_L$	-	40	80	ns
		CP to QPn; see Figure 6	5 V	$123\text{ ns} + (0.55\text{ ns/pF}) C_L$	-	150	300	ns
			10 V	$59\text{ ns} + (0.23\text{ ns/pF}) C_L$	-	70	140	ns
			15 V	$47\text{ ns} + (0.16\text{ ns/pF}) C_L$	-	55	110	ns
		STR to QPn; see Figure 7	5 V	$73\text{ ns} + (0.55\text{ ns/pF}) C_L$	-	100	200	ns
			10 V	$34\text{ ns} + (0.23\text{ ns/pF}) C_L$	-	45	90	ns
			15 V	$27\text{ ns} + (0.16\text{ ns/pF}) C_L$	-	35	70	ns
t_t	transition time		5 V	[1] $10\text{ ns} + (1.00\text{ ns/pF}) C_L$	-	60	120	ns
			10 V	$9\text{ ns} + (0.42\text{ ns/pF}) C_L$	-	30	60	ns
			15 V	$6\text{ ns} + (0.28\text{ ns/pF}) C_L$	-	20	40	ns
t_{PZH}	OFF-state to HIGH propagation delay	OE to QPn; see Figure 8	5 V		-	40	80	ns
			10 V		-	25	50	ns
			15 V		-	20	40	ns
t_{PZL}	OFF-state to LOW propagation delay	OE to QPn; see Figure 8	5 V		-	40	80	ns
			10 V		-	25	50	ns
			15 V		-	20	40	ns
t_{PHZ}	HIGH to OFF-state propagation delay	OE to QPn; see Figure 8	5 V		-	75	150	ns
			10 V		-	40	80	ns
			15 V		-	30	60	ns

Table 7. Dynamic characteristics ...continued $V_{SS} = 0\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$; for test circuit see [Figure 10](#); unless otherwise specified.

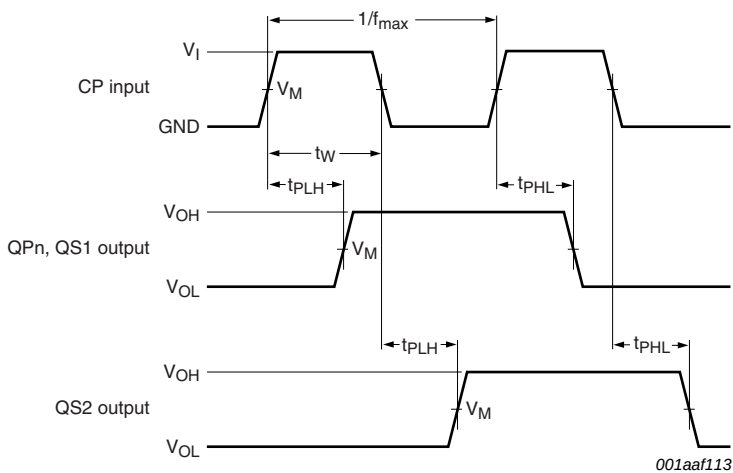
Symbol	Parameter	Conditions	V_{DD}	Extrapolation formula	Min	Typ	Max	Unit
t_{PLZ}	LOW to OFF-state propagation delay	OE to QPn; see Figure 8	5 V		-	80	160	ns
			10 V		-	40	80	ns
			15 V		-	30	60	ns
t_{su}	set-up time	D to CP; see Figure 9	5 V		60	30	-	ns
			10 V		20	10	-	ns
			15 V		15	5	-	ns
t_h	hold time	D to CP; see Figure 9	5 V		+5	-15	-	ns
			10 V		20	5	-	ns
			15 V		20	5	-	ns
t_w	pulse width	minimum LOW clock pulse; see Figure 6	5 V		60	30	-	ns
			10 V		30	15	-	ns
			15 V		24	12	-	ns
		minimum HIGH strobe pulse; see Figure 7	5 V		40	20	-	ns
			10 V		30	15	-	ns
			15 V		24	12	-	ns
f_{max}	maximum frequency	see Figure 6	5 V		5	10	-	MHz
			10 V		11	22	-	MHz
			15 V		14	28	-	MHz

[1] The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C_L in pF).

Table 8. Dynamic power dissipation $V_{SS} = 0\text{ V}$; $t_r = t_f \leq 20\text{ ns}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$.

Symbol	Parameter	V_{DD}	Typical formula for P_D (μW)	where:
P_D	dynamic power dissipation	5 V	$P_D = 2100 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$	f_i = input frequency in MHz,
		10 V	$P_D = 9700 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$	f_o = output frequency in MHz,
		15 V	$P_D = 26000 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$	C_L = output load capacitance in pF, V_{DD} = supply voltage in V, $\Sigma(f_o \times C_L)$ = sum of the outputs.

11. Waveforms

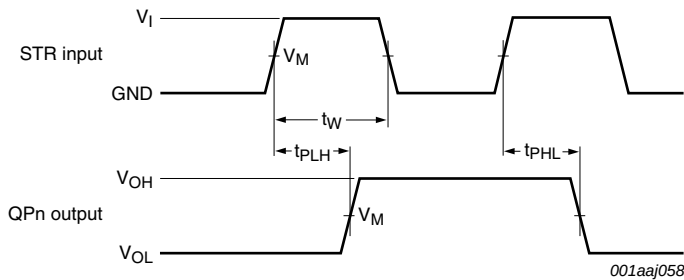


Measurement points are given in [Table 9](#).
Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 6. Clock to outputs propagation delays, and clock pulse width and maximum frequency

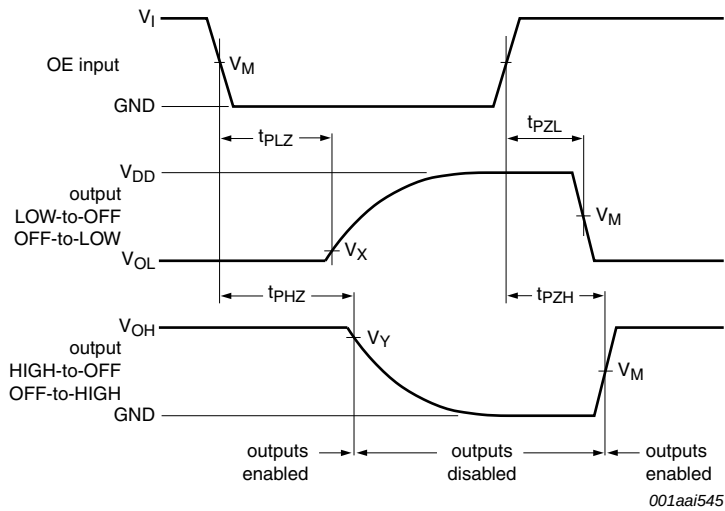
Table 9. Measurement points

Supply voltage	Input	Output		
V_{DD}	V_M	V_M	V_X	V_Y
5 V to 15 V	$0.5V_{DD}$	$0.5V_{DD}$	$0.1V_{DD}$	$0.9V_{DD}$



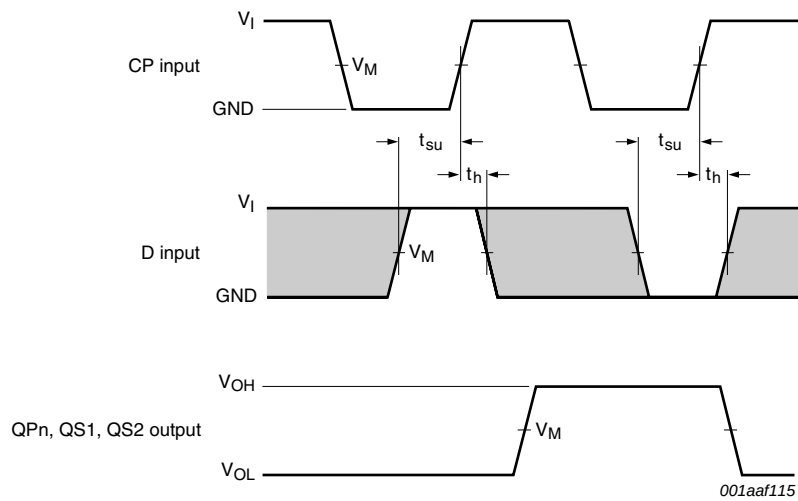
Measurement points are given in [Table 9](#).
Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 7. Strobe to output propagation delays, and strobe pulse width, set up and hold times



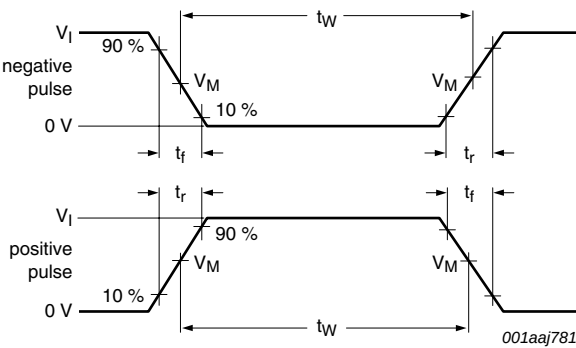
Measurement points are given in [Table 9](#).
Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 8. 3-state output enable and disable times for OE input

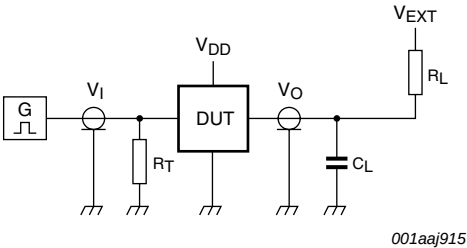


Measurement points are given in [Table 9](#).
Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 9. Data input data set up and hold times



a. Input waveform



b. Test circuit

Test data is given in [Table 10](#).
Definitions for test circuit:
DUT = Device Under Test.
 C_L = load capacitance including jig and probe capacitance.
 R_L = load resistance.
 R_T = termination resistance should be equal to the output impedance Z_o of the pulse generator.

Fig 10. Test circuit

Table 10. Test data

Supply voltage	Input		V_{EXT}			Load	
V_{DD}	V_I	t_r, t_f	t_{PHL}, t_{PLH}	t_{PHZ}, t_{PZH}	t_{PLZ}, t_{PZL}	C_L	R_L
5 V to 15 V	V_{SS} or V_{DD}	≤ 20 ns	open	V_{SS}	V_{DD}	50 pF	1 k Ω

12. Application information

Some examples of applications for the HEF4094B are:

- Serial-to-parallel data conversion
- Remote control holding register

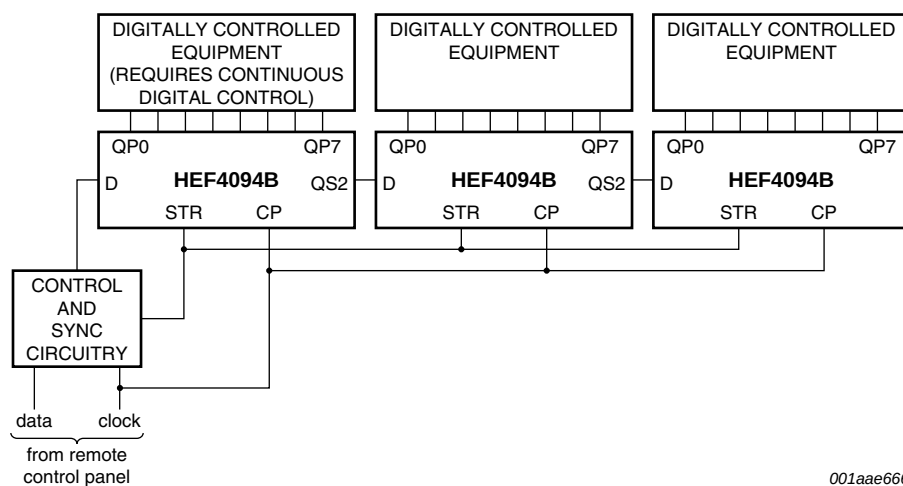


Fig 11. Remote control holding register

13. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4

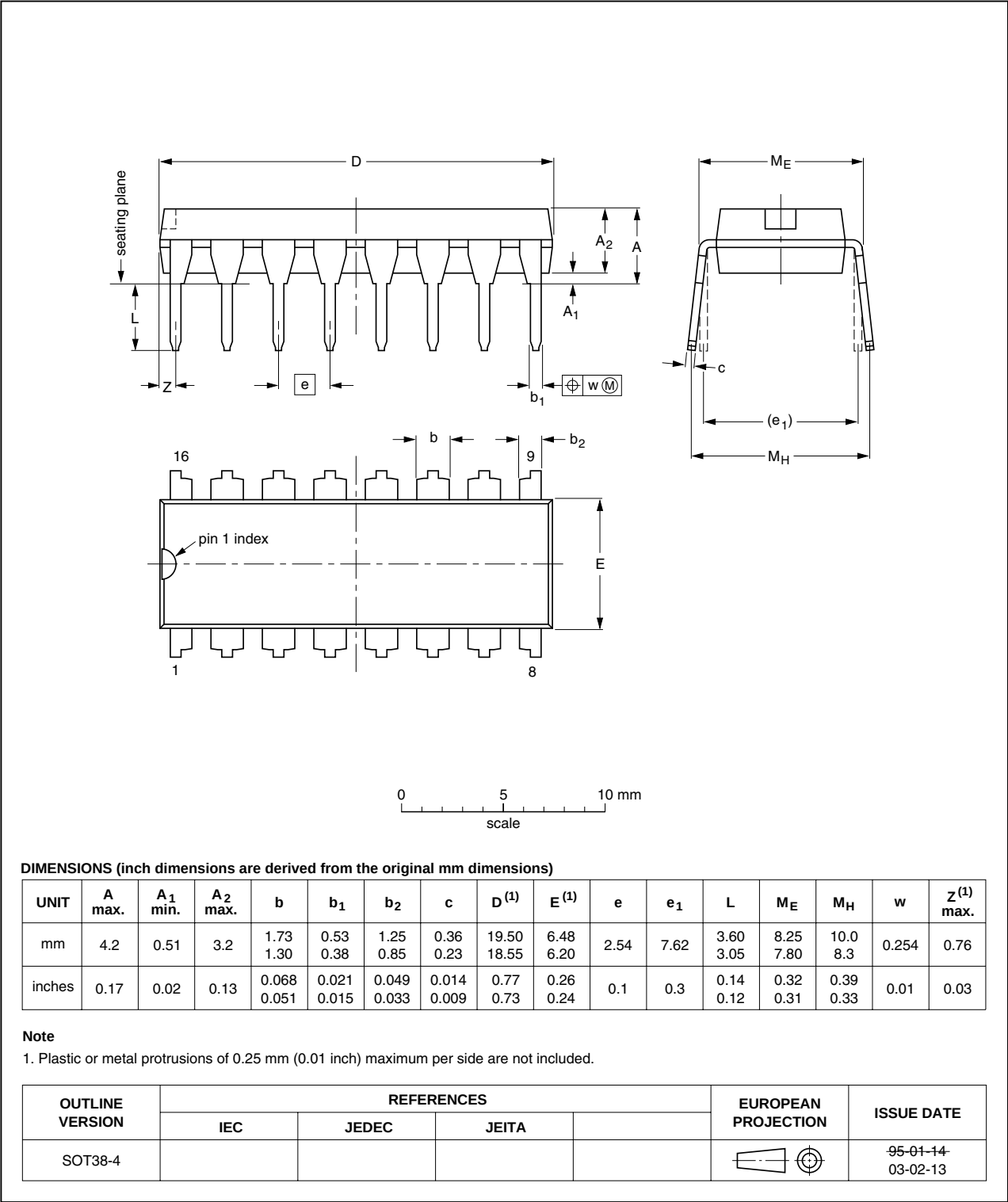


Fig 12. Package outline SOT38-4 (DIP16)

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1

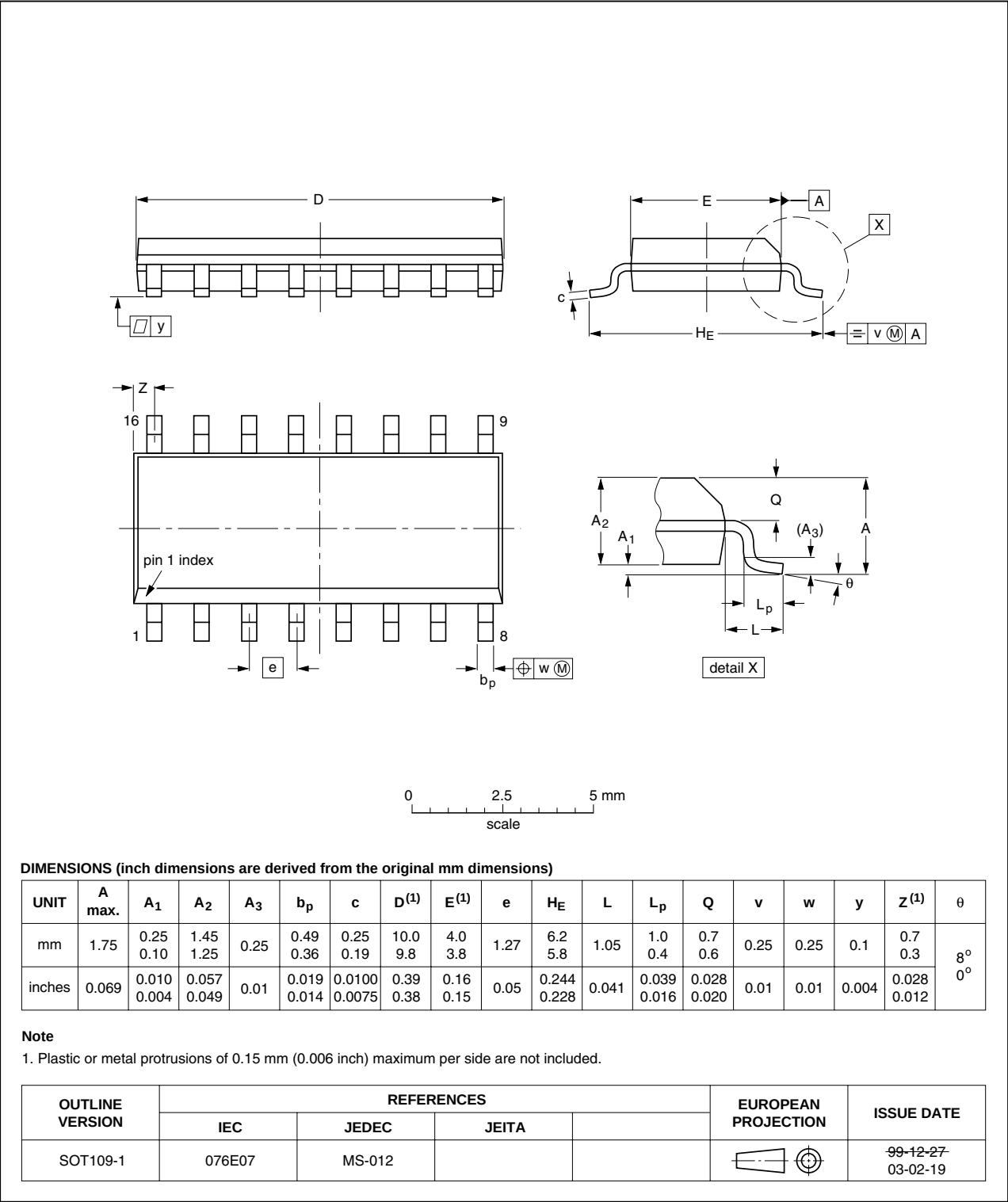


Fig 13. Package outline SOT109-1 (SO16)

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1

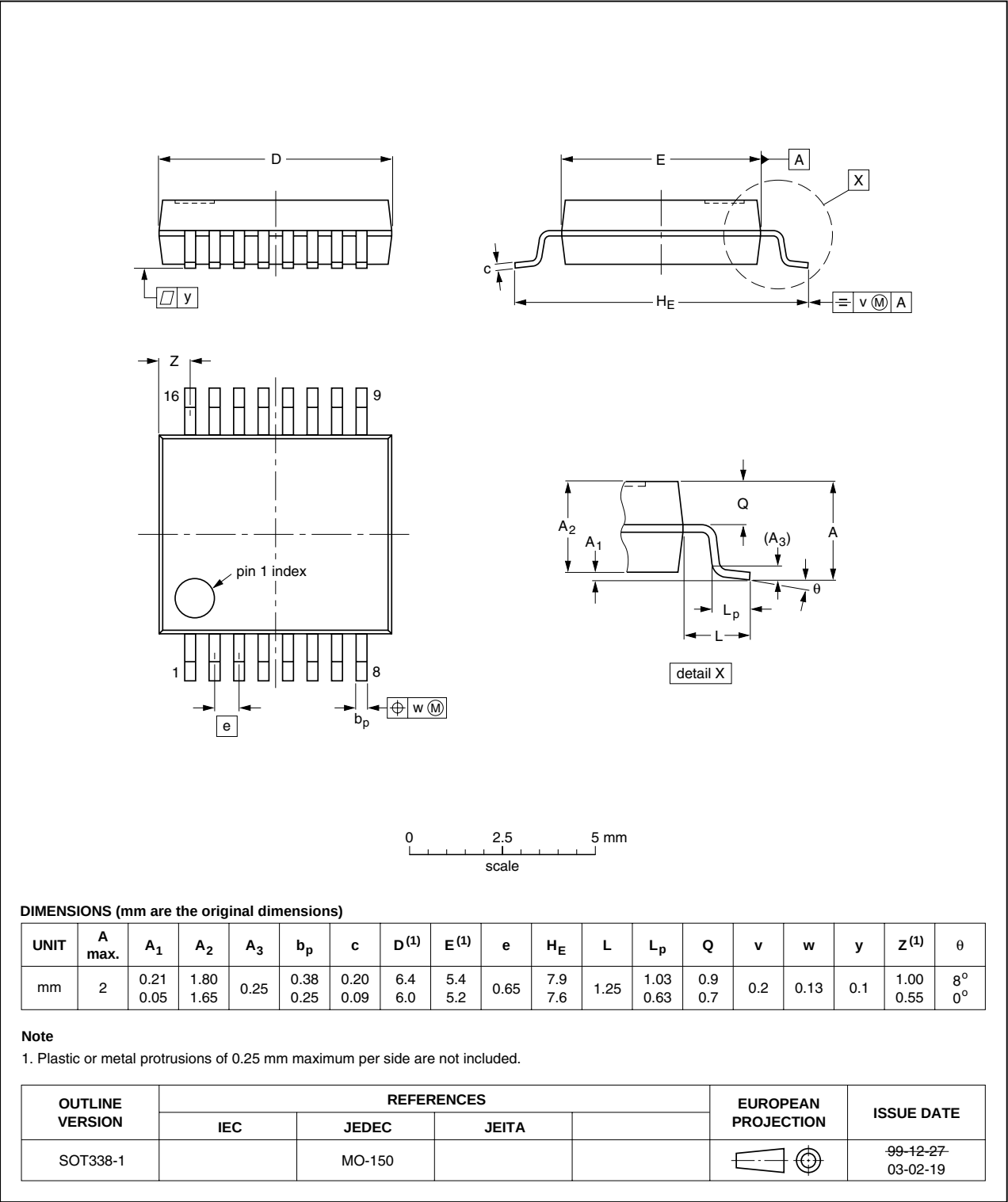


Fig 14. Package outline SOT338-1 (SSOP16)

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4094B_7	20091216	Product data sheet	-	HEF4094B_6
Modifications:	• Section 11 "Waveforms" Figure 10 "Test circuit": updated. • Section 11 "Waveforms" Table 10 "Test data" t_{PHZ} and t_{PZH} and t_{PLZ} and t_{PZL} values updated.			
HEF4094B_6	20091103	Product data sheet	-	HEF4094B_5
HEF4094B_5	20090728	Product data sheet	-	HEF4094B_4
HEF4094B_4	20081030	Product data sheet	-	HEF4094B_CNV_3
HEF4094B_CNV_3	19950101	Product specification	-	HEF4094B_CNV_2
HEF4094B_CNV_2	19950101	Product specification	-	-

15. Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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